## NSN 5962-01-236-6689

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No



View Online at https://aerobasegroup.com/nsn/5962-01-236-6689

0.785 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power Dissip	ation Rating:
332.8 milliwatts	
Operating Tempurature	Range:
-55.0/+125.0 degrees cels	sius
Storage Tempurature Ra	ange:
-65.0/+150.0 degrees cels	sius
Features Provided:	
Hermetically sealed and b	ourn in and bipolar and programmable and w/enable
Inclosure Material:	
Ceramic	
Inclosure Configuration	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Terminal Surface Treatm	nent:
Solder	
Voltage Rating And Typ	e Per Characteristic:
7.0 volts power source	
Time Rating Per Chacte	ristic:
40.00 nanoseconds prop	pagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standa	ard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Qua	ntity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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**Fiig:** A458a0

